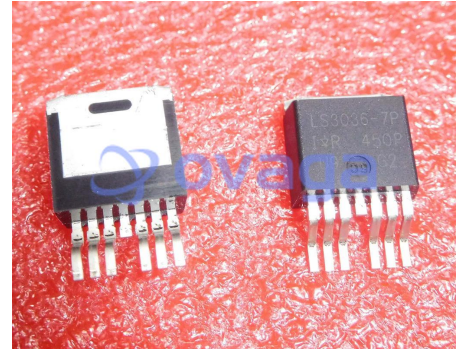


60V Single N-Channel HEXFET Power MOSFET in a D2-Pak 7-Lead package

Manufacturers	<u><a href="#">Infineon Technologies Corporation</a></u>
Package/Case	TO-263-7
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for IRLS3036-7PPBF or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

Optimized for broadest availability from distribution partners

Product qualification according to JEDEC standard

Logic level : Optimized for 10 V gate drive voltage, capable of 4.5 V gate drive voltage

Industry standard surface-mount power package

Higher current-rating (by 23%) vs D2PAK (of same die-size)

High-current carrying capability package (up to 240 A, die-size dependent)

## Features

Optimized for broadest availability from distribution partners

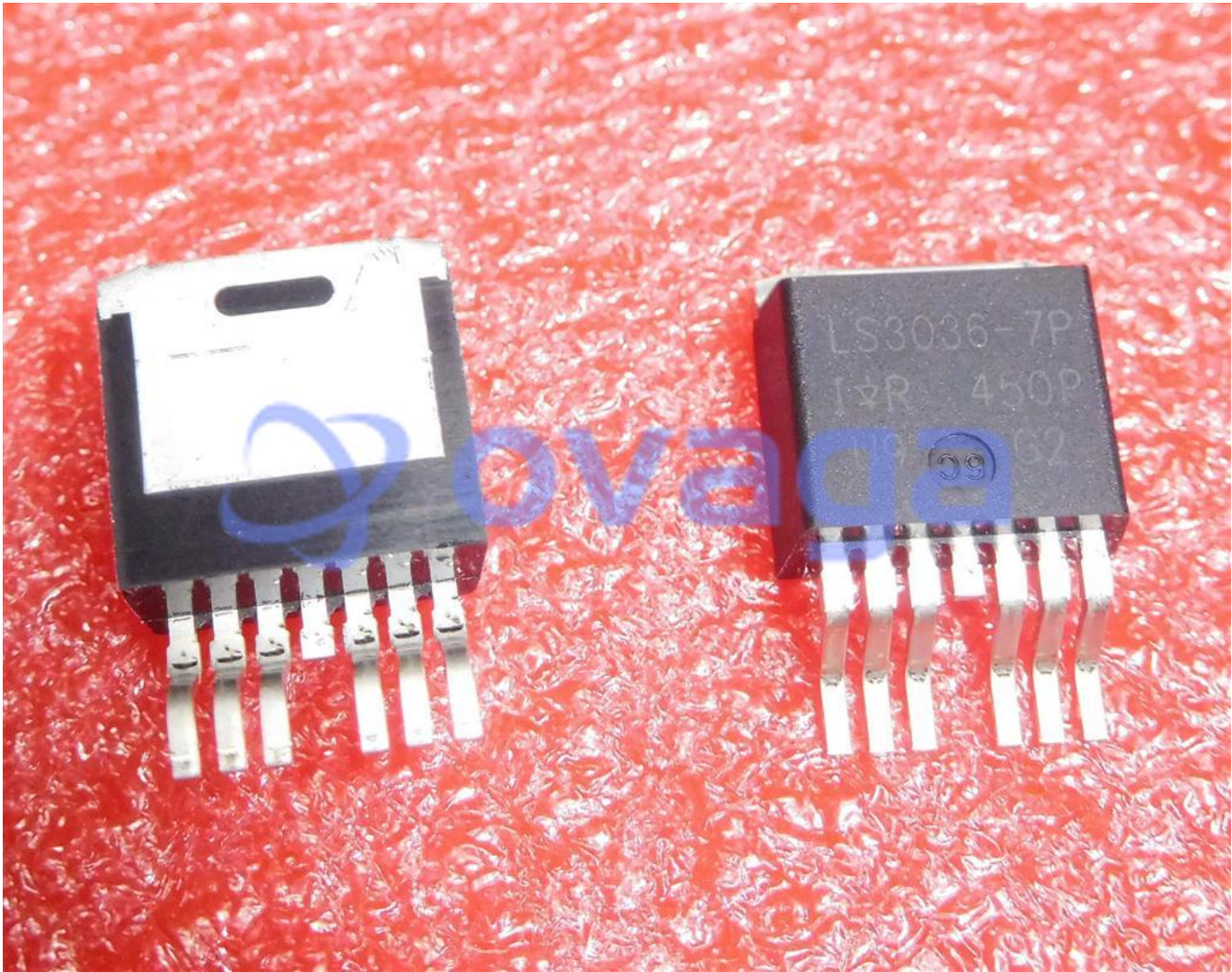
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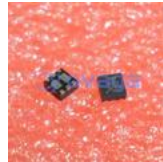


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